

## Electronic Supplementary Information

### **Ferroelectric enhanced Z-scheme P doped g-C<sub>3</sub>N<sub>4</sub>/PANI/BaTiO<sub>3</sub> ternary heterojunction with boosted visible-light photocatalytic water splitting**

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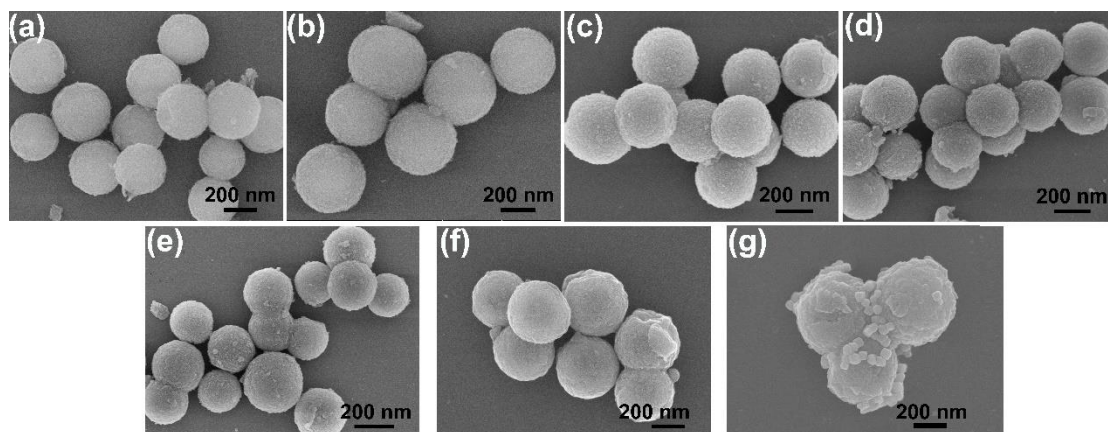
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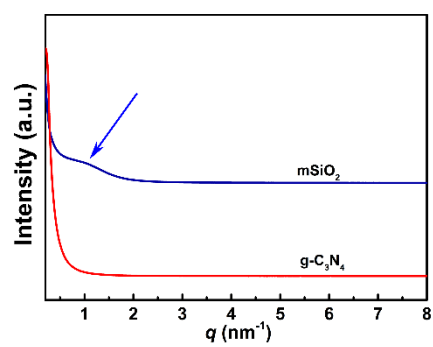
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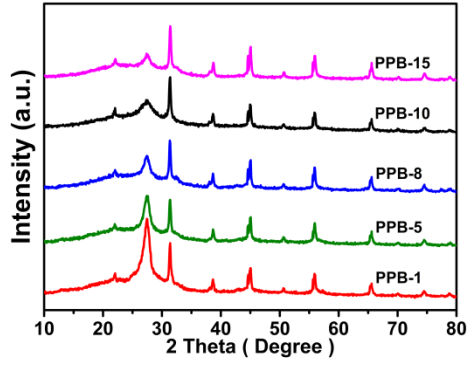
**Theoretical calculation.** To better understand the electronic transfer mechanism involved in the interfaces of photocatalysts, spin-polarized density functional theory calculations were carried out with the Perdew-Burke-Ernzerhof (PBE) exchange correlation functional<sup>1</sup> and projector-augmented wave (PAW) pseudopotentials<sup>2</sup> as implemented in the Vienna ab initio simulation package (VASP)<sup>3,4</sup>. The wave functions were expanded in a plane wave basis with an energy cutoff of 500 eV. The gamma centered scheme K-points grid sampling was set at  $\Gamma$  point for all the calculations. The van der Waals (vdW) interactions were included which were corrected by the DFT-D3 approach<sup>5</sup> and all the structural relaxations were carried out until the residual forces were below 0.02 eV  $\text{\AA}^{-1}$ . To obtain exact band gaps of PCN and PCN/PANI heterostructure, Heyd-Scuseria-Ernzerhof (HSE) hybrid functional with  $\omega$  equals to 0.2  $\text{\AA}^{-1}$  was employed.<sup>6</sup>



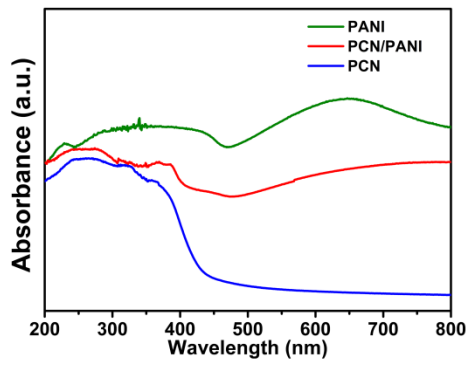
**Fig. S1.** SEM images for the morphology evolution in the synthetic process.



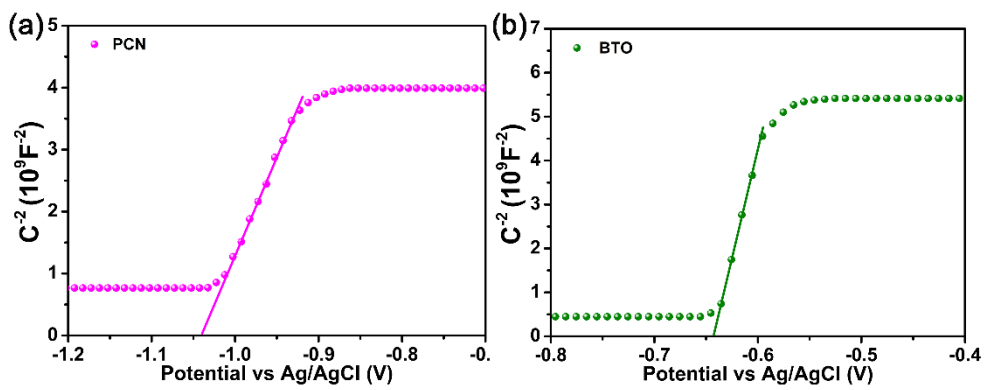
**Fig. S2.** SAXS patterns of mesoporous SiO<sub>2</sub> and g-C<sub>3</sub>N<sub>4</sub>.



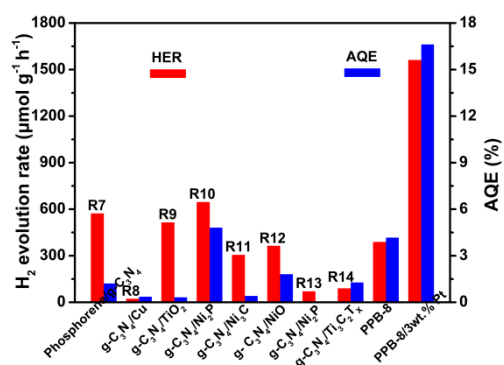
**Fig. S3.** XRD patterns of the PPB- $x$  samples.



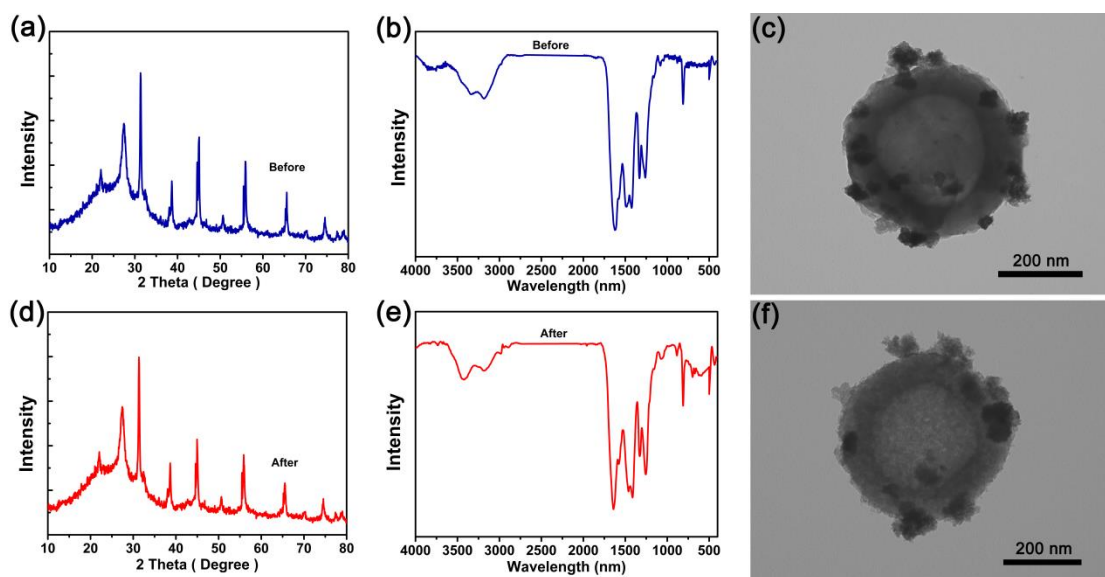
**Fig. S4.** UV-vis diffuse reflectance spectroscopy of PCN, PANI and PCN/PANI.



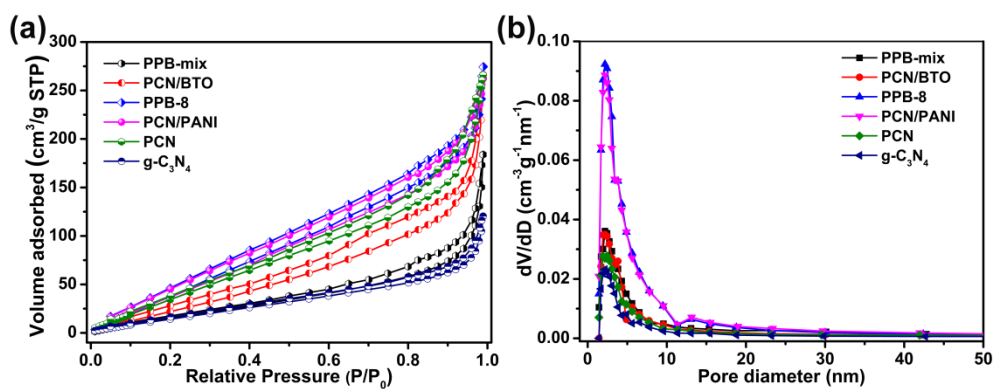
**Fig. S5.** Mott-Schottky plots for PCN and BTO.



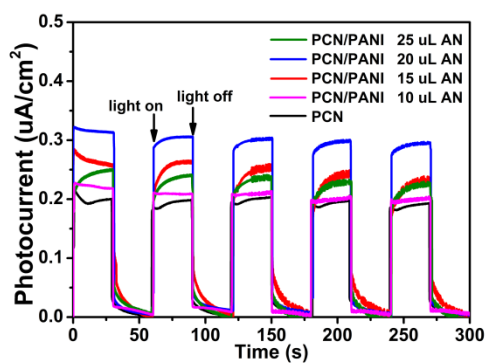
**Fig. S6.** Comparison of H<sub>2</sub> generation and AQE with that reported for other up-to-date g-C<sub>3</sub>N<sub>4</sub> based photocatalysts at 420 nm.



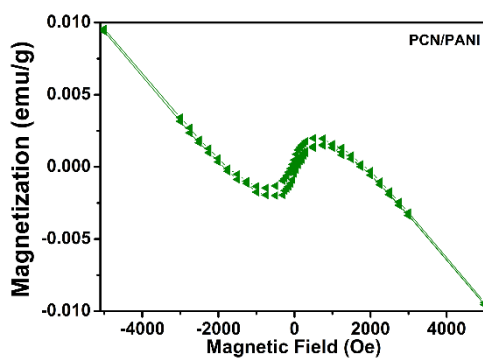
**Fig. S7.** Comparison of XRD, FT-IR and TEM of pristine PPB-8 photocatalyst and sample after six consecutive recycling experiments.



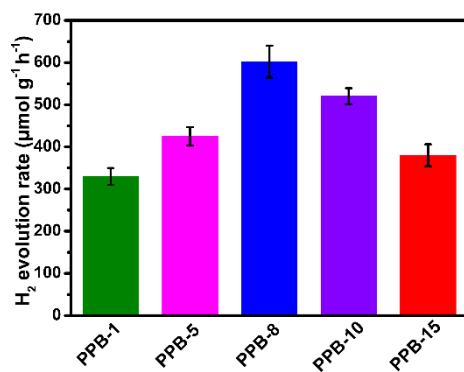
**Fig. S8.** (a) Nitrogen adsorption-desorption isotherms and (b) pore size distribution curve.



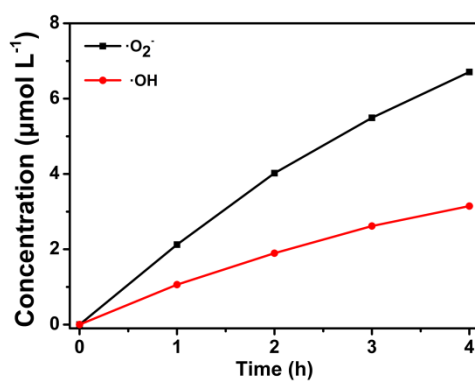
**Fig. S9.** Effect of loading amount of PANI on photocurrent.



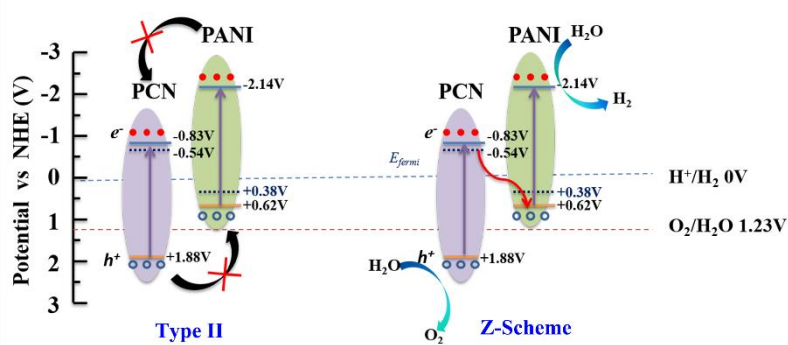
**Fig. S10.** Room temperature magnetic hysteresis loops of PCN/PANI.



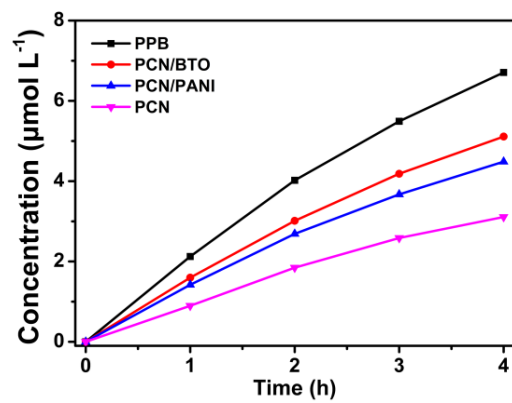
**Fig. S11.** Effect of loading amount of BTO on hydrogen evolution rate.



**Fig. S12.** Quantitative determination of generated •O<sub>2</sub><sup>-</sup> and •OH for PPB.



**Fig.S13.** Schematic diagram for photoinduced electron and hole transfer route in PCN/PANI junction.



**Fig. S14.** Trapping rate comparison for PCN, PCN/PANI, PCN/BTO and PPB.



**Table S1.** Pore structure parameters obtained from the nitrogen desorption isotherm.

<b>Sample</b>	<b>S<sub>bet</sub>/(m<sup>2</sup>/g)</b>	<b>V<sub>Tot</sub>/(cm<sup>3</sup> g<sup>-1</sup>)</b>	<b>D<sub>av</sub>/ (nm)</b>
<b>g-C<sub>3</sub>N<sub>4</sub></b>	86	0.157	9.1
<b>PCN</b>	119	0.186	8.7
<b>PCN/PANI</b>	129	0.406	6.3
<b>PPB-8</b>	132	0.428	6.0
<b>PCN/BTO</b>	111	0.231	10.1
<b>PPB-mix</b>	98	0.224	7.5

**Table S2.** Physicochemical data of PPB-*x*.

<b>Sample</b>	<b>BTO/(PPB) wt.%</b>	<b>Nanoparticle size nm</b>	<b>BET m<sup>2</sup> g<sup>-1</sup></b>	<b>Pore volume cm<sup>3</sup> g<sup>-1</sup></b>	<b>E<sub>g</sub> eV</b>	<b>HER umol g<sup>-1</sup> h<sup>-1</sup></b>
<b>PPB-1</b>	1	40 ± 3	122	0.412	2.52	329
<b>PPB-5</b>	5	40 ± 3	138	0.436	2.51	424
<b>PPB-8</b>	8	40 ± 3	132	0.428	2.51	602
<b>PPB-10</b>	10	40 ± 3	128	0.342	2.51	520
<b>PPB-15</b>	15	40 ± 3	120	0.297	2.50	380

## References

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